

# Dual 4:1 channel analog MUX/DEMUX with injection current protection

Datasheet - production data

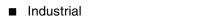
#### **Features**

- Low power dissipation
  - I<sub>CC</sub> = 2  $\mu$ A (max.) at T<sub>A</sub> = 25 °C
- Injection current protection:  $V_{\Delta}$ out < 1 mV at  $V_{CC}$  = 5 V,  $I_{IN}$  = 1 mA,  $R_S$  = 3.9 k $\Omega$
- "ON" resistance at T<sub>A</sub> = 25 °C
  - 215 Ω typ. (V<sub>CC</sub> = 3.0 V)
  - 160 Ω typ. (V<sub>CC</sub> = 4.5 V)
  - 150 Ω typ. (V<sub>CC</sub> = 6 V)
- Fast switching:  $t_{pd} = 8.6$  ns (typ.) at  $T_A = 25$  °C,  $V_{CC} = 4.5$  V
- Wide operating supply voltage range
  - $V_{CC} = 2 V \text{ to } 6 V$
- High noise immunity: V<sub>NIH</sub> = V<sub>NIL</sub> = 28% V<sub>CC</sub> (min.)
- Pin and function compatible with series 4052, 4852
- Latch-up performance exceeds 500 mA
  - (JESD 17)
- ESD performance
  - HBM: 2000 VMM: 200 V
  - CDM: 1000 V

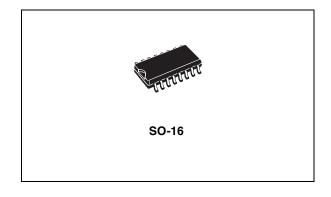
#### **Applications**

- Automotive
- Computer
- Consumer

Table 1.



**Device summary** 



#### **Description**

The M74HC4852 device is a dual four-channel analog multiplexer/demultiplexer manufactured with silicon gate C<sup>2</sup>MOS technology.

It features injection current effect control which makes the device particularly suited for use in automotive applications where voltages in excess of normal logic voltage are common. The injection current effect control allows signals at disabled input channels to exceed the supply voltage range or go down to ground without affecting the signal of the enabled analog channel.

This eliminates the need for external dioderesistor networks typically used to keep the analog channel signals within the supply voltage range.

Order code	Temperature range	Package	Packaging	Marking	
M74HC4852RM13TR	-55/+125 °C	SO16	Tape and reel	74HC4852	
M74HC4852YRM13TR <sup>(1)</sup>	-40/+125 °C	SO16 (automotive grade)	Tape and reel	74HC4852Y	

Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q002 or equivalent.

Pin connections M74HC4852

#### 1 Pin connections

Figure 1. Pin connections and IEC logic symbols

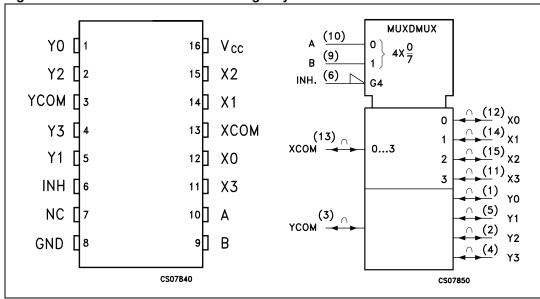


Table 2. Pin descriptions

Pin number	Symbol	Name and function
3, 13	YCOM, XCOM	Common output/input
6	INH	INHIBIT input
7	NC	Not connected
10, 9	A, B	Select inputs
12, 14, 15, 11, 1, 5, 2, 4	X0 to X3, Y0 to Y3	Independent input/outputs
8	GND	Ground (0 V)
16	V <sub>CC</sub>	Positive supply voltage

Table 3. Truth table

	Input state	On channel				
INH	В	Α	On ondinier			
L	L	L	X0	Y0		
L	L	Н	X1	Y1		
L	Н	L	X2	Y2		
L	Н	Н	Х3	Y3		
Н	Х	Х	NONE	NONE		

Note: X: don't care.

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M74HC4852 Pin connections

Figure 2. Control input equivalent circuit

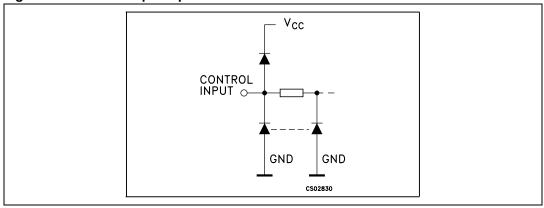


Figure 3. I/O equivalent circuit

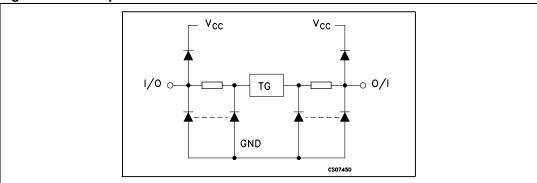
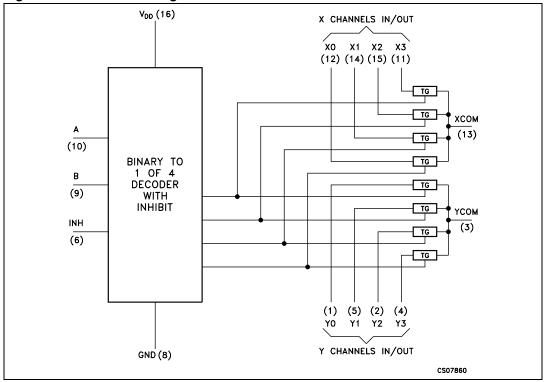


Figure 4. Functional diagram



# 2 Absolute maximum ratings and operating conditions

Note:

Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

Table 4. Absolute maximum ratings

Symbol	Paramet	er	Value	Unit	
V <sub>CC</sub>	Supply voltage		-0.5 to +7	V	
V <sub>IN</sub>	Control input voltage	Control input voltage			
V <sub>I/O</sub>	Switch I/O voltage	-0.5 to V <sub>CC</sub> + 0.5	V		
I <sub>CK</sub>	Control input diode current	Control input diode current			
I <sub>IOK</sub>	I/O diode current	I/O diode current			
I <sub>CC</sub>	DC V <sub>CC</sub> or ground current		± 50	mA	
P <sub>D</sub>	Power dissipation	SO-16	500 <sup>(1)</sup>	mW	
T <sub>stg</sub>	Storage temperature		-65 to +150	°C	
T <sub>L</sub>	Lead temperature (10 sec.)		300	°C	
_	Human body model (HBM)	Human body model (HBM)			
ESD (JESD22)	Machine model (MM)	200	V		
(3-3-2-)	Charged device model (CDM)		1000	V	

<sup>1.</sup> Power dissipation at 65 °C. Derating from 65 °C to 125 °C: SO package -7 mW/°C.

Table 5. Recommended operating conditions

Symbol	Parameter		Value	Unit
V <sub>CC</sub>	Supply voltage		2 to 6	V
V <sub>I/O</sub>	Input output voltage		0 to V <sub>CC</sub>	V
V <sub>I/O</sub>	Static or dynamic voltage across switch	h <sup>(1)</sup>	0 to 1.2	V
V <sub>IN</sub>	Control input voltage	0 to V <sub>CC</sub>	V	
т	Operating temperature	SO16		°C
T <sub>op</sub>	Operating temperature	SO16 (automotive grade)	-40 to +125	°C
		V <sub>CC</sub> = 2.0 V	0 to 1000	ns
	(2)	V <sub>CC</sub> = 3.0.V	0 to 800	
t <sub>r</sub> , t <sub>f</sub>	Input rise and fall time <sup>(2)</sup> (channel select or enable inputs only)	V <sub>CC</sub> = 3.3 V	0 to 700	
	, and the second	V <sub>CC</sub> = 4.5 V	0 to 500	
		V <sub>CC</sub> = 6.0 V	0 to 400	

For voltage drops across the switch greater than 1.2 V (switch on), excessive V<sub>CC</sub> current may be drawn; i.e., the current out of the switch may contain both V<sub>CC</sub> and switch input components. The reliability of the device is unaffected unless the maximum ratings are exceeded.

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<sup>2.</sup>  $V_{IN}$  from 30% to 70%  $V_{CC}$  of channel selected or enable inputs.

Table 6. DC specifications

		Test condition						Value	)			
Symbol	Parameter	v <sub>cc</sub>			T,	\ = 25	°C	Up to	85 °C	Up to 125 °C		Unit
		(V)			Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
		2.0			1.5			1.5		1.5		
		3.0			2.1			2.1		2.1		
V <sub>IHC</sub>	High level input voltage	3.0			2.3			2.3		2.3		V
		4.5			3.15			3.15		3.15		
		6.0			4.2			4.2		4.2		
		2.0					0.5		0.5		0.5	
	Low lovel incom	3.0					0.9		0.9		0.9	
V <sub>ILC</sub>	Low level input voltage	3.3					1.0		1.0		1.0	V
	voltage	4.5					1.35		1.35		1.35	1
		6.0					1.8		1.8		1.8	
		2.0	I <sub>S</sub> = 2 mA			500	650		670		700	
		3.0	· I <sub>S</sub> ≤2 mA	$V_{IN} = V_{IHC}$		215	280		320		360	Ω
R <sub>ON</sub>	ON resistance	3.3		or $V_{ILC}$ $V_{IS} = V_{CC}$ to		210	270		305		345	
		4.5		GND		160	210		240		270	
		6.0				150	195		220		250	
		2.0	I <sub>S</sub> = 2 mA			4	10		15		20	
	Difference of	3.0				2	8		12		16	
$\Delta R_{ON}$	ON resistance between	3.3		$V_{IN} = V_{IHC}$ or $V_{ILC}$ $V_{IS} = V_{CC}/2$		2	8		12		16	Ω
	switches	4.5	I <sub>S</sub> ≤2 mA	$V_{IS} = V_{CC}/2$		2	8		12		16	
		6.0				3	9		13		18	
I <sub>OFF</sub>	Input/output leakage current (switch off) (any channel)	6.0					±0.1		±0.5		±1.0	μА
I <sub>OFF</sub>	Input/output leakage current (switch off) (common channel)	6.0	$V_{IN} = V_{CC}$ or GND				±0.2		±2		±4	μА
I <sub>ON</sub>	Switch input leakage current (switch on, output open)	6.0	$V_{IN} = V_0$	<sub>CC</sub> or GND			±0.1		±0.5		±1	μА



Table 6. DC specifications (continued)

		Test condition		Value							
		ν <sub>cc</sub>	V <sub>CC</sub> (V)		T <sub>A</sub> = 25 °C			Up to 85 °C		Up to 125 °C	
					Тур.	Max.	Min.	Max.	Min.	Max.	
I <sub>IN</sub>	Control input current	6.0	$V_{IN} = V_{CC}$ or GND			±0.1		±0.1		±1	μА
I <sub>CC</sub>	Quiescent supply current	6.0	$V_{IN} = V_{CC}$ or GND $V_{IN (analog)} = GND$			2		20		40	μА

Table 7. AC electrical characteristics ( $C_L = 50 \text{ pF}$ , input  $t_r = t_f = 6 \text{ ns}$ )

		Test condition		Value									
Symbol	Parameter	v <sub>cc</sub>	Test circuit 1	T <sub>A</sub> = 25 °C			Up to	85 °C	Up to	125 °C	Unit		
				(V)	rest circuit i	Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
		2.0			19.5	25		29		32			
t <sub>PHL</sub> , t <sub>PLH</sub> Propagation delay time, analog input to analog output		3.0			12	15.5		17.5		19.5			
	3.3			11	14.5		16.5		18.5	ns			
	4.5			8.6	11.5		12.5		13.5				
		6.0			8	10		11		12			
		2.0			23	30		35		40			
	Propagation	3.0			13.5	17.5		20		23	ns		
t <sub>PHL,</sub> t <sub>PLH</sub>	delay time channel-select	3.3			12.5	16.5		19		22			
T LII	to analog output	4.5			10	13		15		17			
		6.0			9.5	12.5		14.5		16.5			
		2.0				95		105		115			
t <sub>PHZ</sub> ,	Enable disable	3.0				90		100		110			
$t_{PZH}$ $t_{PLZ,},$	time, enable or channel-select	3.3				85		95		105	ns		
$t_{PZL}$	to analog output	4.5				80		90		100			
		6.0				78		80		80			
C <sub>IN</sub>	Input capacitance (digital pins)				3.5	10		10		10	pF		
C <sub>IN</sub>	Input capacitance (switches off, any single analog pins)				6.7	15		15		15	pF		

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Table 7. AC electrical characteristics ( $C_L = 50 \text{ pF}$ , input  $t_r = t_f = 6 \text{ ns}$ ) (continued)

		Test condition		Value							
Symbol	Parameter	V <sub>CC</sub> (V) Test circuit 1	To an advantage	T <sub>A</sub> = 25 °C			Up to 85 °C		Up to 125 °C		Unit
			rest circuit i	Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
C <sub>IN</sub>	Input capacitance (switches off, any common analog pins)				22	40		40		40	pF
Power	3.3			24						=	
C <sub>PD</sub>	dissipation capacitance <sup>(1)</sup>	5.0			28						pF

C<sub>PD</sub> is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load (refer to *Figure 5*). The average operating current can be obtained by the following equation: I<sub>CC</sub> (opr.) = C<sub>PD</sub> x V<sub>CC</sub> x f<sub>IN</sub> + I<sub>CC</sub>/8.

Table 8. Injection current coupling specification ( $T_A = -55$  °C to +125 °C)

		Те	st condition	Va		
Symbol	Parameter	arameter  V <sub>CC</sub> (V)  Test circuit 2  Typ. (1)		Typ. <sup>(1)</sup>	Max.	Unit
		3.3	L <1mA D <20k0	0.050	1.0	
Chift of		5.0	$I_{\text{IN}} \le 1 \text{ mA}, R_{\text{S}} \le 3.9 \text{ k}\Omega$	0.100	1.0	
	Chift of autous	3.3	L < 10 m A D < 0.0 kg	0.345	5.0	
V	Shift of output voltage of	5.0	$I_{IN} \le 10 \text{ mA}, R_S \le 3.9 \text{ k}\Omega$	0.067	5.0	mV
$V_{\Delta OUT}$	enabled analog channel	3.3	$I_{IN} \le 1 \text{ mA}, R_S \le 20 \text{ k}\Omega$	0.050	2.0	IIIV
	Chamie	5.0	11N = 1 111A, ng = 20 ks2	0.110	2.0	
	3.3	$I_{IN} \le 10 \text{ mA}, R_S \le 20 \text{ k}\Omega$	0.050	20		
		5.0	IN = 10 IIIA, 115 = 20 K22	0.024	20	

Typical values are measured at T<sub>A</sub> = 25 °C. They are calculated as the difference from V<sub>OUT</sub> without injection current and V<sub>OUT</sub> with injection current. I<sub>IN</sub> = total current injected into any other disabled channels, one at time.

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Figure 5. Test circuit 1

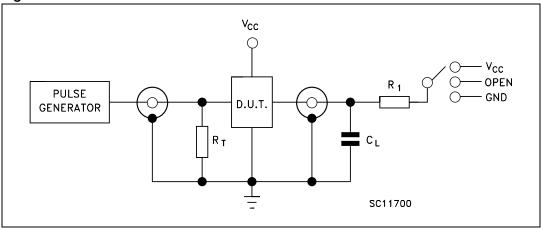


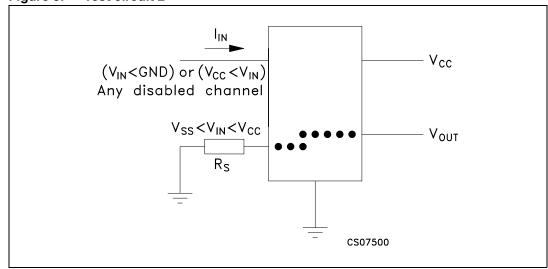
Table 9. Test circuit 1 - switch configuration table

Test	Switch
t <sub>PLH</sub> , t <sub>PHL</sub>	Open
t <sub>PZL</sub> , t <sub>PLZ</sub>	V <sub>CC</sub>
t <sub>PZH</sub> , t <sub>PHZ</sub>	GND

Note:

 $C_L$  = 50 pF or equivalent (includes jig and probe capacitance).  $R_L$  = R1 = 10 k $\Omega$  or equivalent.  $R_T$  =  $Z_{OUT}$  of pulse generator (typically 50  $\Omega$ ).

Figure 6. Test circuit 2



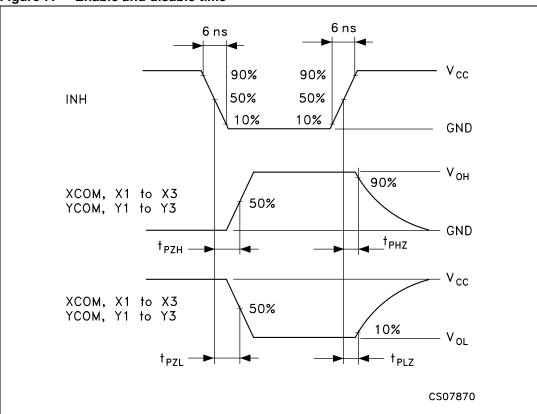
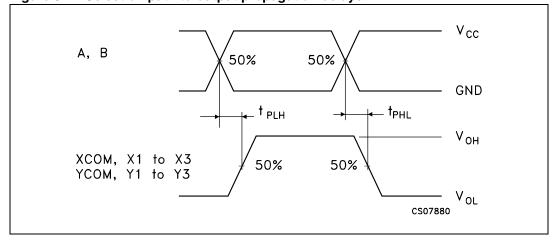


Figure 7. Enable and disable time





ANALOG IN XCOM, X1 to X3 YCOM, Y1 to Y3

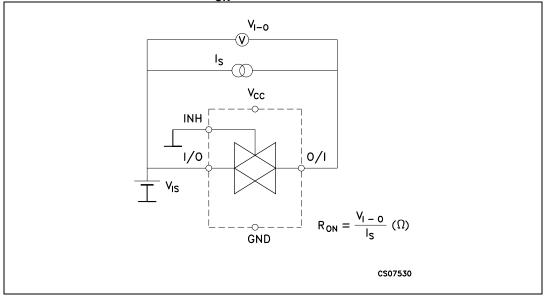
ANALOG OUT XCOM, X1 to X3 YCOM, Y1 to Y3

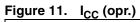
ANALOG OUT XCOM, X1 to X3 YCOM, Y1 to Y3

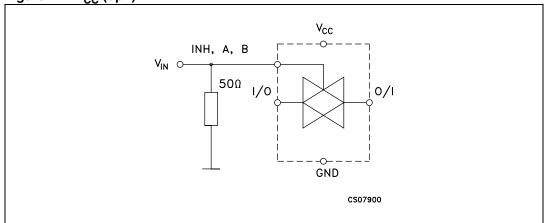
Vol

Figure 9. Input (COM, 0 to 7 in) to output (0 to 7 out, COM) propagation delays









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M74HC4852 Package information

### 3 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: <a href="www.st.com">www.st.com</a>. ECOPACK is an ST trademark.

Package information M74HC4852

### 3.1 SO-16 package information

Figure 12. SO-16 package outline

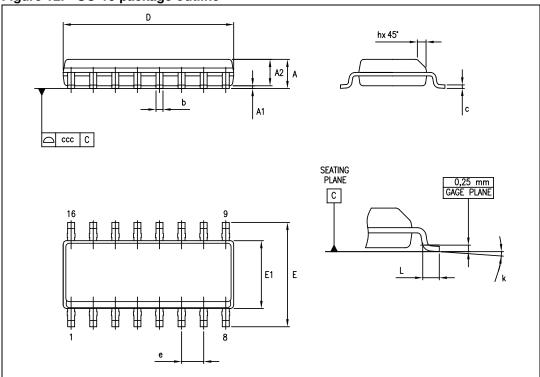


Table 10. SO-16 package mechanical data

			Dimer	nsions				
Symbol		Millimeters		Inches				
	Min.	Тур.	Max.	Min.	Тур.	Max.		
Α			1.75			0.069		
A1	0.10		0.25	0.004		0.010		
A2	1.25			0.049				
b	0.31		0.51	0.012		0.020		
С	0.17		0.25	0.007		0.010		
D	9.80	9.90	10.00	0.386	0.390	0.394		
E	5.80	6.00	6.20	0.228	0.236	0.244		
E1	3.80	3.90	4.00	0.150	0.154	0.157		
е		1.27			0.050			
h	0.25		0.50	0.010		0.020		
L	0.40		1.27	0.016		0.050		
k	0		8					
ccc			0.10			0.004		

# 4 Ordering information

Table 11. Order codes

Order code	Temperature range	Package	Packaging	Marking
M74HC4852RM13TR	-55/+125 °C	SO-16		74HC4852
M74HC4852YRM13TR <sup>(1)</sup>	-40/+125 °C	SO-16 (automotive grade)	Tape and reel	74HC4852Y

Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q002 or equivalent.

Revision history M74HC4852

# 5 Revision history

Table 12. Document revision history

Date	Revision	Changes
05-Apr-2012	5	Document reformatted.  Added ESD charged device model feature on cover page.  Added ESD values to Table 4: Absolute maximum ratings.  Modified Chapter 3: Package information.  Modified Chapter 4: Ordering information.
15-Jun-2012	Corrected ON-resistance values in Features on page 1 Added Applications on page 1 Shortened Description on page 1 Added Table 1: Device summary on page 1 Updated Top in Table 5: Recommended operating conditions Updated Table 11: Order codes on page 13	
18-Oct-2012	Updated ESD values in <i>Features</i> .  Updated <i>Table 1</i> (added Packaging and Marking, updated not Updated <i>Table 11</i> (updated note 1).  Minor corrections throughout document.	

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